## NSN 5962-01-281-6644

Memory Microcircuit - Page 1 of 1

**Fiig:** A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-281-6644

| Body Length:   |
|--|
| Between 1.130 inches and 1.260 inches  |
| Body Width:  |
| Between 0.475 inches and 0.530 inches  |
| Body Height:   |
| 0.160 inches   |
| Maximum Power Dissipation Rating:  |
| 525.0 milliwatts   |
| Operating Tempurature Range:   |
| -55.0/+125.0 degrees celsius   |
| Storage Tempurature Range:   |
| -65.0/+125.0 degrees celsius   |
| Features Provided:   |
| Electrostatic sensitive and w/enable and hermetically sealed and ultraviolet erasable and programmable                               |
| Inclosure Material:  |
| Ceramic  |
| Inclosure Configuration:   |
| Dual-in-line   |
| Output Logic Form:   |
| Metal oxide-semiconductor logic  |
| Input Circuit Pattern:   |
| 14 input   |
| Terminal Surface Treatment:  |
| Solder   |
| Voltage Rating And Type Per Characteristic:  |
| 26.5 volts power source  |
| Time Rating Per Chacteristic:  |
| 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level |
| output   |
| Memory Device Type:  |
| Rom  |
| Test Data Document:  |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).                   |
| Terminal Type And Quantity:  |
| 24 printed circuit   |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
|  |
| Demilitarization:  |
| Yes - demil/mli  |